

INFORMATION  
DISCLOSURE  
CITATION FORM FOR  
PATENT APPLICATION  
(FORM PTO - 1449)

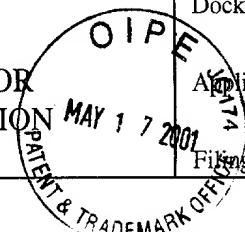
Docket No.: 3536 C02

Serial No.: 09/775,295

Applicant(s): JAMES CARDUCCI, ET AL.

Filing Date: 01-31-01

Group: 1700



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MAY 21 2001  
**TC 1700**

## U. S. PATENTS

Initials	Patent No	Issue Date	Name	CRS	Status	Filing Date
gray	4,438,723	03-27-84	CANNELLA ET AL.			
	4,440,107	04-03-84	DOEHLER ET AL.			
	4,483,737	11-20-84	MANTEI			
	4,810,935	03-07-89	BOSWELL			
	4,842,707	06-27-89	KINOSHITA			
	4,990,229	02-05-91	CAMPBELL ET AL.			
	4,993,361	02-19-91	UNVALA			
	5,091,049	02-25-92	CAMPBELL ET AL.			
	5,122,251	06-16-92	CAMPBELL ET AL.			
	5,160,398	11-03-92	YANAGIDA			
	5,178,739	01-12-93	BARNES ET AL.			
	5,224,441	07-06-93	FELTS ET AL.			
gray	5,346,579	09-13-94	COOK ET AL.			

## FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	Considered
gray	EP 0 173 583	05.03.86	EUROPE	KIM KUYNGSHIK ET AL.	NO
	EP 0 651 425	03.05.95	EUROPE	ROBERT CHAPMAN	NO
	EP 0 786 794	03.07.97	EUROPE	PETER LOEWENHARDT ET AL.	NO
gray	7-22389	24.01.95	JAPAN	YUTAKA KAKCHI ET AL.	NO

Initials Other Documents (Title, Author, Date, Pages, Etc., if known)

gray Quick, A.K., Chen, R.T.S., and Hershkowitz, N., "Etch rate and plasma density radial uniformity measurements in a cusped field helicon plasma etcher," *J. Vac. Sci. Technol.*, Vol. 14, No. 3, May/June 1996, pp. 1041-1045.

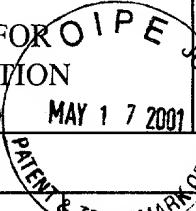
Examiner's Signature:

*George Gouldreau*

Date Considered:

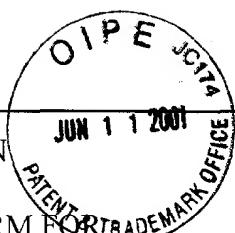
9-03

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<b>INFORMATION DISCLOSURE CITATION FORM FOR MPEP PATENT APPLICATION (FORM PTO - 1449)</b>  <b>MAY 17 2001</b>		Docket No.: 3536 C02	Serial No.: 09/775,295		
		Applicant(s): JAMES CARDUCCI, ET AL.			
		Filing Date: 01-31-01	Group: 105 1763		
<b>U. S. PATENTS</b>					
Initials	Patent No	Issue Date	Name		
<i>gag</i>	5,401,351	03-28-95	SAMUKAWA		
	5,421,891	06-06-95	CAMPBELL ET AL.		
	5,429,070	07-04-95	CAMPBELL ET AL.		
	5,484,485	01-16-96	CHAPMAN		
	5,556,501	09-17-96	COLLINS ET AL.		
	5,662,819	09-02-97	KADOMURA		
	6,030,486	02-29-00	LOEWENHARDT, ET AL.		
	6,054,013	04-25-00	COLLINS, ET AL.		
<b>FOREIGN PATENT DOCUMENTS</b>					
Initials	Document Number	Date	Country	Name	Translation? (Yes/No/n/a)
<b>Initials</b>	<b>Other Documents (Title, Author, Date, Pages, Etc., if known)</b>				
<i>gag</i>	U.S. Patent Application Serial No. 09/263,001, Filed March 5, 1999, entitled, "Magnetically Enhanced Inductively Coupled Plasma Reactor with Magnetically Confined Plasma," by Gerald Yin, et al.				
	U.S. Patent Application Serial No. 09/521,799, Filed March 9, 2000, entitled, "Magnetically Enhanced Inductively Coupled Plasma Reactor with Magnetically Confined Plasma," by Gerald Yin, et al.				
<i>gag</i>	U.S. Patent Application Serial No. 09/773, 409, Filed January 31, 2001, entitled, "Magnetically Enhanced Inductively Coupled Plasma Reactor with Magnetically Confined Plasma," by Peter Loewenhardt, et al.				
Examiner's Signature: <i>George Gould Ream</i>			Date Considered: <i>9-031</i>		
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INFORMATION  
DISCLOSURE  
CITATION FORM FOR TRADEMARK OFFICE  
PATENT APPLICATION  
(FORM PTO - 1449)

Docket No.: 3536 C02 Serial No.: 09/775,291

Applicant(s): JAMES CARDUCCI, ET AL.

Filing Date: 01-31-01

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JUN 13 2001

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U. S. PATENTS

Initials	Patent No	Issue Date	Name	Class	Subclass	Filing Date
GAG	6,074,518	06-13-00	IMAFUKU ET AL.	156	345	01-04-99
GAG	6,189,484	02-20-01	YIN ET AL.	118	723	03-05-99

FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	Translation? (Yes/No/n/a)

Initials Other Documents (Title, Author, Date, Pages, Etc., if known)

Examiner's Signature:

George Goudreau

Date Considered:

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Docket No.: 3536 C02 Serial No.: 09/775,295

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Filing Date: 01-31-01 Group: 1763

## U. S. PATENTS

Initials	Patent No	Issue Date	Name	Class	Subclass	Filing Date

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## FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	Translations (Fee Waived)
gpy	HEI 8-264515	11.10.96	JAPAN	MITSUYOSHI IMAFUKU ET AL.	N/A

Initials	Other Documents (Title, Author, Date, Pages, Etc., if known)

Examiner's Signature:

George Gaudrean

Date Considered:

9-03-1

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